Hyperfast Rectifier, 8 A FRED Pt^{TM}

8ETH06S

Base cathode

D^{2}PAK

8ETH06-1

TO-262
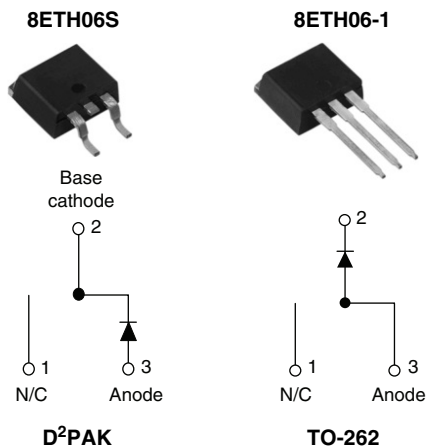
FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Designed and qualified for industrial level

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRODUCT SUMMARY

t_{rr} (typical)	18 ns
$I_{F(AV)}$	8 A
V_R	600 V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	T_C = 144 °C	8	
Non-repetitive peak surge current	I_{FSM}	T_J = 25 °C	90	A
Peak repetitive forward current	I_{FM}		16	
Operating junction and storage temperatures	T_J, T_{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 µA	600	-	-	V
Forward voltage	V_F	I_F = 8 A	-	2.0	2.4	
		I_F = 8 A, T_J = 150 °C	-	1.3	1.8	
Reverse leakage current	I_R	V_R = V_R rated	-	0.3	50	µA
		T_J = 150 °C, V_R = V_R rated	-	55	500	
Junction capacitance	C_T	V_R = 600 V	-	17	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8.0	-	nH

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Hyperfast Rectifier,
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DYNAMIC RECOVERY CHARACTERISTICS (T_C = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	I_F = 1 A, dI_F/dt = 100 A/μs, V_R = 30 V		-	18	22	ns
		I_F = 8 A, dI_F/dt = 100 A/μs, V_R = 30 V		-	20	25	
		T_J = 25 °C	I_F = 8 A dI_F/dt = 200 A/μs V_R = 390 V	-	25	-	
		T_J = 125 °C		-	40	-	
Peak recovery current	I_{RRM}	T_J = 25 °C		-	2.4	-	A
		T_J = 125 °C		-	4.8	-	
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	25	-	nC
		T_J = 125 °C		-	120	-	
Reverse recovery time	t_{rr}	T_J = 125 °C	I_F = 8 A dI_F/dt = 600 A/μs V_R = 390 V	-	33	-	ns
Peak recovery current	I_{RRM}			-	12	-	A
Reverse recovery charge	Q_{rr}			-	220	-	nC

THERMAL - MECHANICAL SPECIFICATIONS

| PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 65	-	175	°C
Thermal resistance, junction to case per leg	R_{thJC}		-	1.4	2	°C/W
Thermal resistance, junction to ambient per leg	R_{thJA}	Typical socket mount	-	-	70	
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style D²PAK		8ETH06S		
		Case style TO-262		8ETH06-1		

Hyperfast Rectifier,
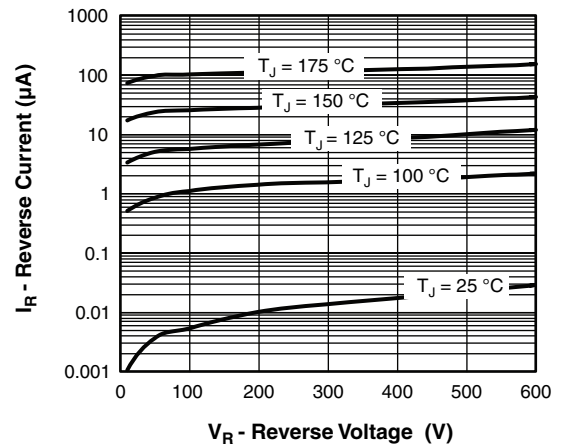8 A FRED Pt[TM]
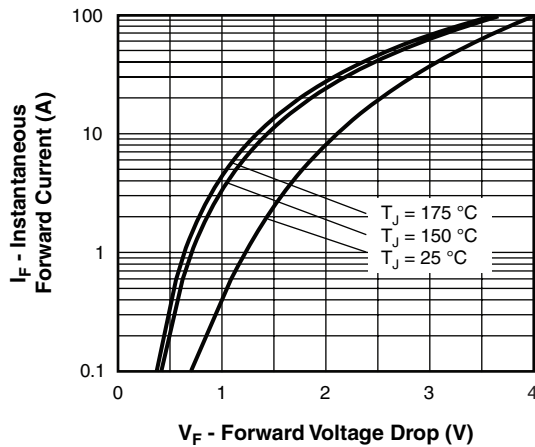
Fig. 1 - Typical Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

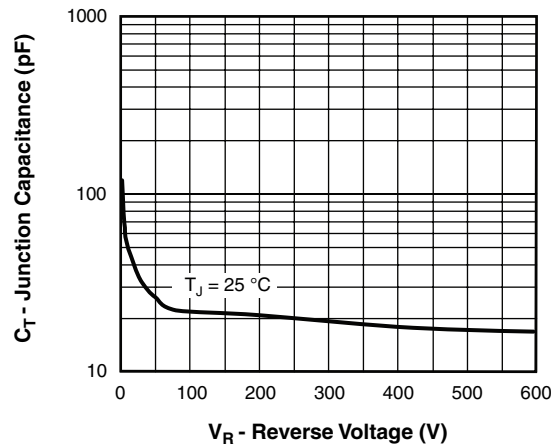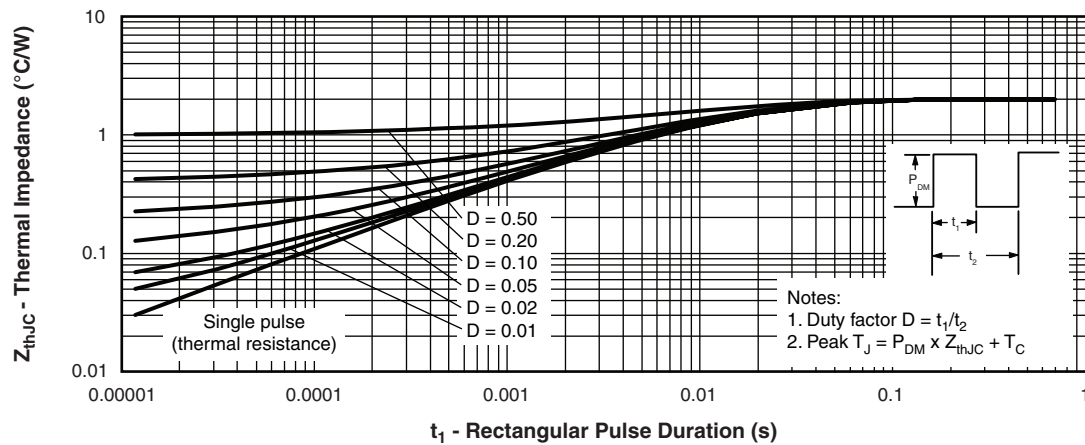Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

Notes:
1. Duty factor $D = t_1/t_2$
2. Peak $T_J = P_{DM} \times Z_{thJC} + T_C$

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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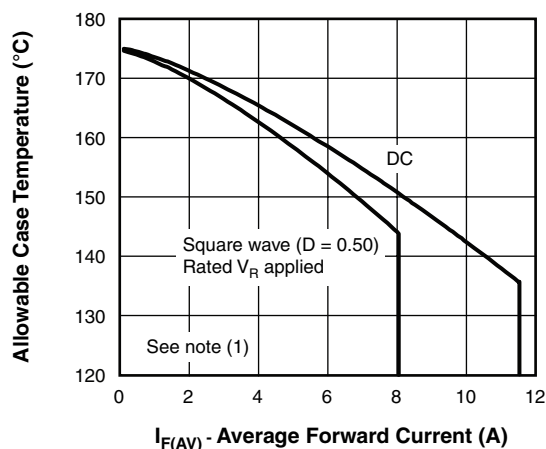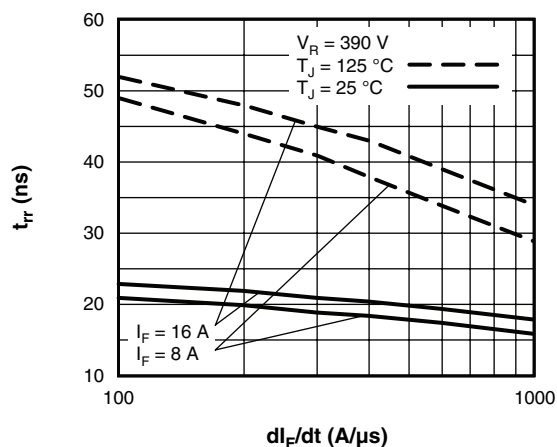Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt
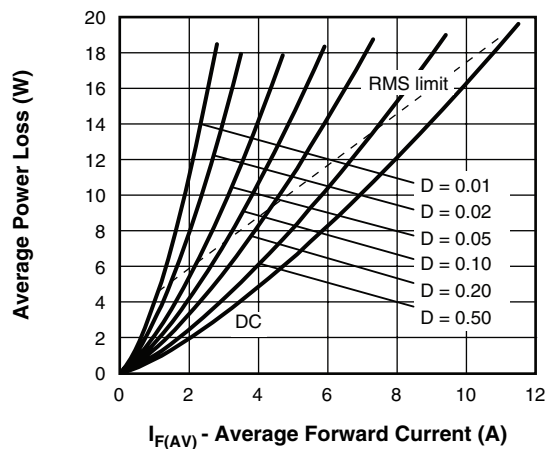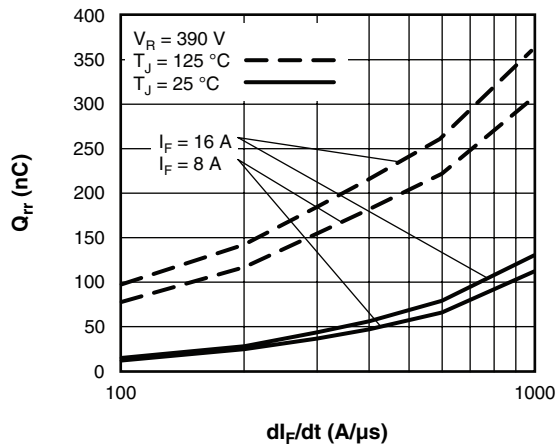
Fig. 6 - Forward Power Loss Characteristics

Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

[1] Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
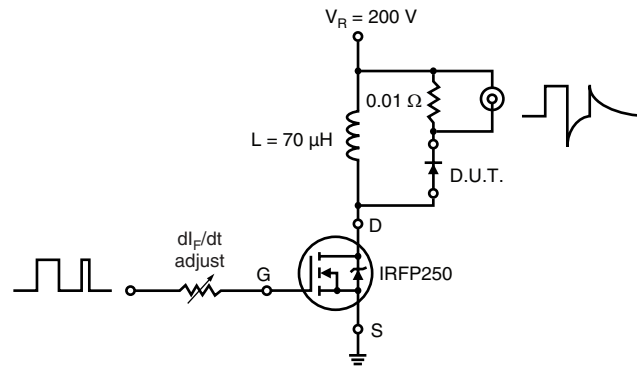Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

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V_R = 200 V

0.01 Ω

L = 70 µH

D.U.T.

D

dI_F/dt
adjust

G

IRFP250

S

Fig. 9 - Reverse Recovery Parameter Test Circuit

I_F

0

(3)

t_{rr}

t_a

t_b

Q_{rr} (4)

(2) I_{RRM}

0.5 I_{RRM}

$dI_{(rec)M}/dt$ (5)

0.75 I_{RRM}

(1) dI_F/dt

(1) dI_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	8	E	T	H	06	S	TRL	-
	①	②	③	④	⑤	⑥	⑦	⑧

|1| - Current rating (8 A)

|2| - E = Single diode

|3| - T = TO-220, D^2PAK

|4| - H = Hyperfast recovery

|5| - Voltage rating (06 = 600 V)

|6| - • S = D^2PAK

    • -1 = TO-262

|7| - • None = Tube (50 pieces)

    • TRL = Tape and reel (left oriented, for D^2PAK package)

    • TRR = Tape and reel (right oriented, for D^2PAK package)

|8| - • None = Standard production

    • PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95014
Part marking information	http://www.vishay.com/doc?95008
Packaging information	http://www.vishay.com/doc?95032

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